

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MA2SP060G

Silicon planar type

For high frequency switch

■ Features

• Low terminal capacitance: $C_t \le 0.6 \text{ pF}$ • Low forward dynamic resistance: $r_f \le 1.2 \Omega$

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Reverse voltage	V_R	60	V
Forward current	I_F	100	mA
Junction temperature	Tj	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Package

Code

SSMini2-F4

Pin Name

1: Anode

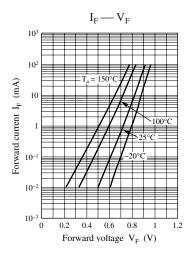
2: Cathode

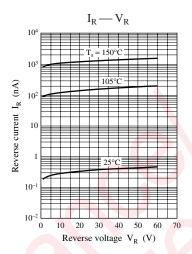
■ Marking Symbol: 6P

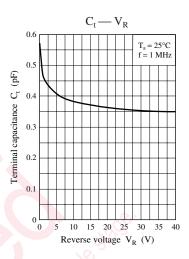
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

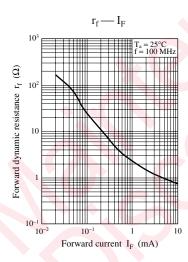
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\rm F}$	$I_F = 10 \text{ mA}$	37.1	0.85	1.0	V
Reverse current	I _R	$V_R = 60 \text{ V}$	0///	1.0	100	nA
Terminal capacitance	Ct	$V_R = 1 \text{ V, } f = 1 \text{ MHz}$	90	0.45	0.6	pF
Forward dynamic resistance	$r_{\rm f}$	$I_F = 10 \text{ mA}, f = 100 \text{ MHz}$	20/1	0.80	1.2	Ω

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.



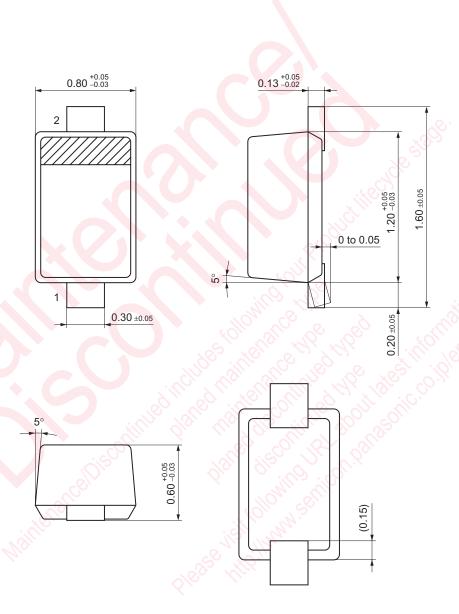






2 SKL00031AED

SSMini2-F4 Unit: mm



SKL00031AED 3

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